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Supplementary Information

Valley splitting and anomalous valley Hall effect in MoTe₂/CrSCl heterostructure

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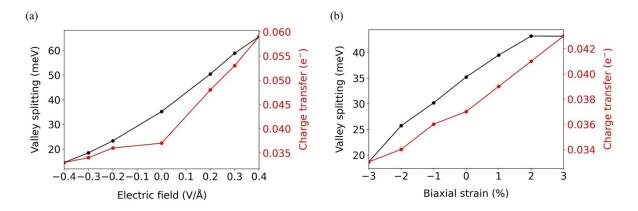


Fig. S1 Valley splitting (black line) and interlayer charge transfer (red line) as functions of (a) the applied electric field and (b) the in-plane biaxial strain.